MB10H100CT, MF10H100CT

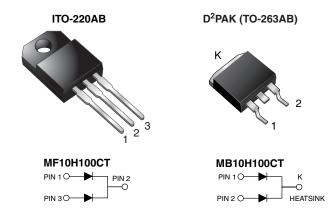
Vishay General Semiconductor

HALOGEN

FREE

Dual Common Cathode High Voltage Schottky Rectifier

High Barrier Technology for Improved High Temperature Performance



PRIMARY CHARACTERISTICS					
I _{F(AV)}	2 x 5 A				
V_{RRM}	100 V				
I _{FSM}	150 A				
V _F	0.61 V				
I _R	3.5 μΑ				
T _J max.	175 °C				
Package	ITO-220AB, D ² PAK (TO-263AB)				
Circuit configuration	Common cathode				

FEATURES

- Power pack
- · Guardring for overvoltage protection
- Low power loss, high efficiency
- Low forward voltage drop
- · Low leakage current
- High forward surge capability
- High frequency operation
- Meets MSL level 1, per J-STD-020, LF maximum peak of 245 °C (for D²PAK (TO-263AB) package)
- Solder bath temperature 275 °C maximum, 10 s, per JESD 22-B106 (for ITO-220AB package)
- AEC-Q101 qualified
- Material categorization: for definitions of compliance please see <u>www.vishay.com/doc?99912</u>

TYPICAL APPLICATIONS

For use in high frequency rectifier of switching mode power supplies, freewheeling diodes, DC/DC converters, and polarity protection application.

MECHANICAL DATA

Case: ITO-220AB, D2PAK (TO-263AB)

Molding compound meets UL 94 V-0 flammability rating

Base P/NHE3_X - RoHS-compliant, AEC-Q101 qualified ("_X" denotes revision code e.g. A, B,....)

(_X denotes revision code e.g. /i, b,....)

Base P/NHM3 - RoHS-compliant, halogen-free, AEC-Q101 qualified

Terminals: matte tin plated leads, solderable per J-STD-002 and JESD 22-B102

J-51 D-002 and JE5D 22-B102

 $\ensuremath{\mathsf{HE3}}$ and $\ensuremath{\mathsf{HM3}}$ suffix meets JESD 201 class 2 whisker test

Polarity: as marked

Mounting Torque: 10 in-lbs maximum

MAXIMUM RATINGS (T _C = 25 °C unless otherwise noted)							
PARAMETER		SYMBOL	MB10H100CT	MF10H100CT	UNIT		
Maximum repetitive peak reverse voltage		V_{RRM}	100				
Working peak reverse voltage		V_{RWM}	100		V		
Maximum DC blocking voltage		V_{DC}	100				
Maximum average forward rectified current at T _C = 105 °C	total device	I _{F(AV)}	10				
Maximum average forward rectified current at 1 _C = 105 °C	per diode		5.0				
Peak forward surge current 8.3 ms single half sine-wave superimposed on rated load per diode		I _{FSM}	150		Α		
Peak repetitive reverse current per diode at t _p = 2.0 μs, 1 kHz		I _{RRM}	0.	0.5			
Voltage rate of change (rated V _R)		dV/dt	10 0	000	V/µs		
Operating junction and storage temperature range		T _J , T _{STG}	-65 to	+175	°C		
Isolation voltage (ITO-220AB only) from terminal to heatsink t = 1 min		V _{AC}	150	00	V		

MB10H100CT, MF10H100CT

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ELECTRICAL CHARACTERISTICS (T _C = 25 °C unless otherwise noted)						
PARAMETER	SYMBOL	TEST CO	NDITIONS	VALUE	UNIT	
Maximum instantaneous forward voltage per diode	V _F ⁽¹⁾	I _F = 5 A	T _J = 25 °C	0.76		
		I _F = 5 A	T _J = 125 °C	0.61	V	
		I _F = 10 A	T _J = 25 °C	0.85		
		I _F = 10 A	T _J = 125 °C	0.71		
Maximum reverse current per diode	I _R ⁽¹⁾	I _R (1) Rated V _R	T _J = 25 °C	3.5	μΑ	
			T _J = 100 °C	4.5	mA	

Notes

 $^{(1)}\,$ Pulse test: 300 μs pulse width, 1 % duty cycle

(2) Pulse test: pulse width ≤ 40 ms

THERMAL CHARACTERISTICS (T _C = 25 °C unless otherwise noted)					
PARAMETER	SYMBOL	MB10H100CT	MF10H100CT	UNIT	
Typical thermal resistance per diode	$R_{ heta JC}$	2.2	5.2	°C/W	

ORDERING INFORMATION							
PACKAGE	PREFERRED P/N	UNIT WEIGHT (g)	PACKAGE CODE	BASE QUANTITY	DELIVERY MODE		
ITO-220AB	MF10H100CTHE3_B/P	1.79	Р	50/tube	Tube		
D ² PAK (TO-263AB)	MB10H100CTHM3/I	1.35	I	800/reel	Tape and reel		

RATINGS AND CHARACTERISTICS CURVES (T_C = 25 °C unless otherwise noted)

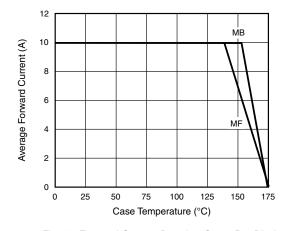


Fig. 1 - Forward Current Derating Curve Per Diode

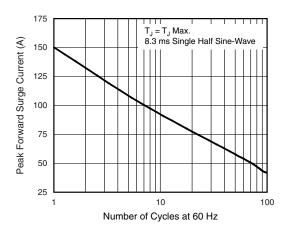


Fig. 2 - Maximum Non-Repetitive Peak Forward Surge Current Per Diode

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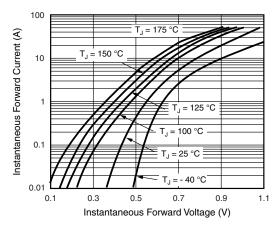


Fig. 3 - Typical Instantaneous Forward Characteristics Per Diode

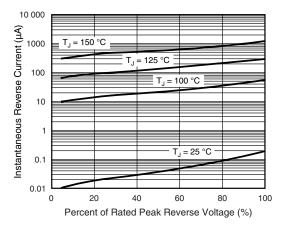


Fig. 4 - Typical Reverse Characteristics Per Diode

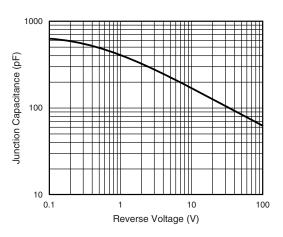


Fig. 5 - Typical Junction Capacitance Per Diode

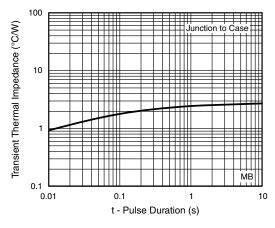


Fig. 6 - Typical Transient Thermal Impedance Per Diode

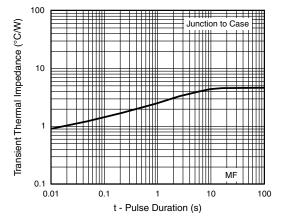
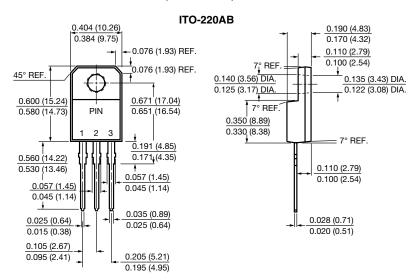


Fig. 7 - Typical Transient Thermal Impedance Per Diode

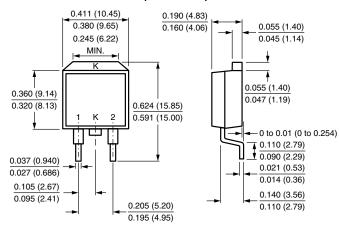
MB10H100CT, MF10H100CT

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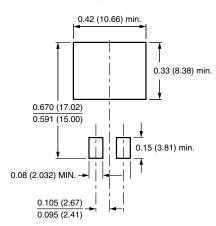
PACKAGE OUTLINE DIMENSIONS in inches (millimeters)



D²PAK (TO-263AB)



Mounting Pad Layout





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